## ZXTN25040DFH

## 40V, SOT23, NPN medium power transistor

## Summary

$B V_{\text {CEX }}>130 \mathrm{~V}$
$\mathrm{BV}_{\text {CEO }}>40 \mathrm{~V}$
$B V_{\text {ECO }}>6 V$
$\mathrm{I}_{\text {(cont) }}=4 \mathrm{~A}$

$\mathrm{V}_{\mathrm{CE}(\text { sat })}<55 \mathrm{mV}$ @ 1A
$R_{\text {CE(sat) }}=\mathbf{3 5} \mathbf{~ m} \Omega$
$P_{D}=1.25 \mathrm{~W}$

## Complementary part number ZXTP25040DFH

## Description

Advanced process capability and package design have been used to maximize the power handling and performance of this small outline transistor. The compact size and ratings of this device make it ideally suited to applications where space is at a premium.

## Features

- High power dissipation SOT23 package

- High peak current
- High gain
- Low saturation voltage
- 130 V forward blocking voltage
- 6V reverse blocking voltage


## Applications

- MOSFET gate drivers
- Power switches
- Motor control


Pinout - top view

- DC fans
- DC-DC converters


## Ordering information

| Device | Reel size <br> (inches) | Tape width <br> $(\mathbf{m m})$ | Quantity per <br> reel |
| :--- | :---: | :---: | :---: |
| ZXTN25040DFHTA | 7 | 8 | 3,000 |

## Device marking

## 1A4

## ZXTN25040DFH

## Absolute maximum ratings

| Parameter | Symbol | Limit | Unit |
| :--- | :---: | :---: | :---: |
| Collector-base voltage | $\mathrm{V}_{\mathrm{CBO}}$ | 130 | V |
| Collector-emitter voltage (forward blocking) | $\mathrm{V}_{\mathrm{CEX}}$ | 130 | V |
| Collector-emitter voltage | $\mathrm{V}_{\mathrm{CEO}}$ | 40 | V |
| Emitter-collector voltage (reverse blocking) | $\mathrm{V}_{\text {ECO }}$ | 6 | V |
| Emitter-base voltage | $\mathrm{V}_{\text {EBO }}$ | 7 | V |
| Continuous collector current ${ }^{(\mathrm{c})}$ | $\mathrm{I}_{\mathrm{C}}$ | 4 | A |
| Base current | $\mathrm{I}_{\mathrm{B}}$ | 1 | A |
| Peak pulse current | $\mathrm{I}_{\mathrm{CM}}$ | 10 | A |
| Power dissipation at $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}^{\text {(a) }}$ | P | 0.73 | W |
| Linear derating factor |  | 5.84 | $\mathrm{~mW} /{ }^{\circ} \mathrm{C}$ |
| Power dissipation at $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}^{(\mathrm{b})}$ |  |  |  |
| Linear derating factor | $\mathrm{P}_{\mathrm{D}}$ | 1.05 | W |
| Power dissipation at $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}^{(\mathrm{c})}$ |  | 8.4 | $\mathrm{~mW} /{ }^{\circ} \mathrm{C}$ |
| Linear derating factor | $\mathrm{P}_{\mathrm{D}}$ | 1.25 | W |
| Power dissipation at $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}^{\text {(d) }}$ |  | 9.6 | $\mathrm{~mW} /{ }^{\circ} \mathrm{C}$ |
| Linear derating factor | $\mathrm{T}_{\mathrm{j}}, \mathrm{T}_{\text {stg }}$ | -55 to 150 | ${ }^{\circ} \mathrm{C}$ |
| Operating and storage temperature range | P | W |  |

## Thermal resistance

| Parameter | Symbol | Limit | Unit |
| :--- | :---: | :---: | :---: |
| Junction to ambient $^{(\mathrm{a})}$ | $\mathrm{R}_{\Theta J A}$ | 171 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Junction to ambient $^{(\mathrm{b})}$ | $\mathrm{R}_{\Theta J A}$ | 119 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Junction to ambient $^{(\mathrm{c})}$ | $\mathrm{R}_{\text {ӨJA }}$ | 100 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Junction to ambient $^{(\mathrm{d})}$ | $\mathrm{R}_{\text {ӨJA }}$ | 69 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## NOTES:

(a) For a device surface mounted on $15 \mathrm{~mm} \times 15 \mathrm{~mm} \times 1.6 \mathrm{~mm}$ FR4 PCB with high coverage of single sided $10 z$ copper, in still air conditions.
(b) Mounted on $25 \mathrm{~mm} \times 25 \mathrm{~mm} \times 1.6 \mathrm{~mm}$ FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions.
(c) Mounted on $50 \mathrm{~mm} \times 50 \mathrm{~mm} \times 1.6 \mathrm{~mm}$ FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions.
(d) As (c) above measured at $\mathrm{t}<5$ secs.

## ZXTN25040DFH

## Characteristics




Transient Thermal Impedance




Pulse Power Dissipation

## ZXTN25040DFH

Electrical characteristics (at $\mathrm{T}_{\mathrm{amb}}=\mathbf{2 5}{ }^{\circ} \mathrm{C}$ unless otherwise stated)

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Collector-base breakdown voltage | BV ${ }_{\text {CBO }}$ | 130 | 170 |  | V | $\mathrm{I}_{\mathrm{C}}=100 \mu \mathrm{~A}$ |
| Collector-emitter breakdown voltage (forward blocking) | $\mathrm{BV}_{\text {CEX }}$ | 130 | 170 |  | V | $\begin{array}{\|l\|} \hline \mathrm{I}_{\mathrm{C}}=100 \mu \mathrm{~A} ; \mathrm{R}_{\mathrm{BE}}<1 \mathrm{k} \Omega \text { or } \\ -1 \mathrm{~V}<\mathrm{V}_{\mathrm{BE}}<0.25 \mathrm{~V} \end{array}$ |
| Collector-emitter breakdown voltage (base open) | $\mathrm{BV}_{\text {CEO }}$ | 40 | 63 |  | V | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}{ }^{(*)}$ |
| Emitter-base breakdown voltage | $B V_{\text {EBO }}$ | 7 | 8.3 |  | V | $\mathrm{I}_{\mathrm{E}}=100 \mu \mathrm{~A}$ |
| Emitter-collector breakdown voltage (reverse blocking) | $\mathrm{BV}_{\mathrm{ECX}}$ | 6 | 7.4 |  | V | $\begin{array}{\|l\|} \hline \mathrm{I}_{\mathrm{E}}=100 \mu \mathrm{~A}, \mathrm{R}_{\mathrm{BC}}<1 \mathrm{k} \Omega \text { or } \\ 0.25 \mathrm{~V}>\mathrm{V}_{\mathrm{BC}}>-0.25 \mathrm{~V} \end{array}$ |
| Emitter-collector breakdown voltage (base open) | $\mathrm{BV}_{\mathrm{ECO}}$ | 6 | 7.4 |  | V | $\mathrm{I}_{\mathrm{E}}=100 \mu \mathrm{~A}$, |
| Collector-base cut-off current | $\mathrm{I}_{\text {CBO }}$ |  | <1 | $\begin{aligned} & 50 \\ & 20 \end{aligned}$ | $\begin{aligned} & \mathrm{nA} \\ & \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{\mathrm{CB}}=100 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CB}}=100 \mathrm{~V}, \mathrm{~T}_{\mathrm{amb}}=100^{\circ} \mathrm{C} \end{aligned}$ |
| Collector-emitter cut-off current | ${ }^{\text {ICEX }}$ |  | - | 100 | nA | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=100 \mathrm{~V} ; \mathrm{R}_{\mathrm{BE}}<1 \mathrm{k} \Omega \\ & \text { or } \\ & -1 \mathrm{~V}<\mathrm{V}_{\mathrm{BE}}<0.25 \mathrm{~V} \end{aligned}$ |
| Emitter-base cut-off current | $\mathrm{I}_{\text {ebo }}$ |  | <1 | 50 | nA | $\mathrm{V}_{\mathrm{EB}}=5.6 \mathrm{~V}$ |
| Collector-emitter saturation voltage | $\mathrm{V}_{\text {CE(sat) }}$ |  | $\begin{gathered} 45 \\ 120 \\ 135 \\ 140 \end{gathered}$ | $\begin{gathered} 55 \\ 210 \\ 210 \\ 190 \end{gathered}$ | $\begin{aligned} & \mathrm{mV} \\ & \mathrm{mV} \\ & \mathrm{mV} \\ & \mathrm{mV} \end{aligned}$ | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=1 \mathrm{~A}, \mathrm{I}_{\mathrm{B}}=100 \mathrm{~mA}^{(*)} \\ & \mathrm{I}_{\mathrm{C}}=1 \mathrm{~A}, \mathrm{I}_{\mathrm{B}}=10 \mathrm{~mA}^{(*)} \\ & \mathrm{I}_{\mathrm{C}}=2 \mathrm{~A}, \mathrm{I}_{\mathrm{B}}=40 \mathrm{~mA}^{(*)} \\ & \mathrm{I}_{\mathrm{C}}=4 \mathrm{~A}, \mathrm{I}_{\mathrm{B}}=400 \mathrm{~mA}^{(*)} \end{aligned}$ |
| Base-emitter saturation voltage | $V_{\text {BE(sat) }}$ |  | 960 | 1050 | mV | $\mathrm{I}_{\mathrm{C}}=4 \mathrm{~A}, \mathrm{I}_{\mathrm{B}}=400 \mathrm{~mA}^{(*)}$ |
| Base-emitter turn-on voltage | $\mathrm{V}_{\mathrm{BE} \text { (on) }}$ |  | 840 | 950 | mV | $\mathrm{I}_{\mathrm{C}}=4 \mathrm{~A}, \mathrm{~V}_{C E}=2 \mathrm{~V}^{(*)}$ |
| Static forward current transfer ratio | $\mathrm{h}_{\text {FE }}$ | $\begin{gathered} 300 \\ 300 \\ 30 \end{gathered}$ | $\begin{gathered} 450 \\ 450 \\ 60 \\ 10 \end{gathered}$ | 900 |  | $\begin{aligned} & \mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=2 \mathrm{~V}^{(*)} \\ & \mathrm{I}_{\mathrm{C}}=1 \mathrm{~A}, \mathrm{~V}_{\mathrm{CE}}=2 \mathrm{~V}^{(*)} \\ & \mathrm{I}_{\mathrm{C}}=4 \mathrm{~A}, \mathrm{~V}_{\mathrm{CE}}=2 \mathrm{~V}^{(*)} \\ & \mathrm{I}_{\mathrm{C}}=10 \mathrm{~A}, \mathrm{~V}_{\mathrm{CE}}=2 \mathrm{~V}^{(*)} \end{aligned}$ |
| Transition frequency | $\mathrm{f}_{\mathrm{T}}$ |  | 190 |  | MHz | $\begin{aligned} & I_{C}=50 \mathrm{~mA}, V_{C E}=10 \mathrm{~V} \\ & \mathrm{f}=100 \mathrm{MHz} \end{aligned}$ |
| Output capacitance | $\mathrm{C}_{\text {Obo }}$ |  | 11.7 | 20 | pF | $\mathrm{V}_{\mathrm{CB}}=10 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}^{(*)}$ |
| Delay time | $\mathrm{t}_{\mathrm{d}}$ |  | 64 |  | ns | $\mathrm{V}_{\mathrm{CC}}=10 \mathrm{~V}$, |
| Rise time | $\mathrm{t}_{\mathrm{r}}$ |  | 108 |  | ns | ${ }^{\text {I }}$ C |
| Storage time | $\mathrm{t}_{\mathrm{s}}$ |  | 428 |  | ns | $\mathrm{B}^{1}=\mathrm{l}_{\mathrm{B} 2}=10$ |
| Fall time | $\mathrm{t}_{\mathrm{f}}$ |  | 130 |  | ns |  |

## NOTES:

${ }^{*}$ ) Measured under pulsed conditions. Pulse width $\leq 300 \mu s$; duty cycle $\leq 2 \%$.

## ZXTN25040DFH

## Typical characteristics



## ZXTN25040DFH

## Package outline - SOT23



| Dim. | Millimeters |  | Inches |  | Dim. | Millimeters |  | Inches |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Min. | Max. | Min. | Max. |  | Min. | Max. | Max. | Max. |
| A | 2.67 | 3.05 | 0.105 | 0.120 | H | 0.33 | 0.51 | 0.013 | 0.020 |
| B | 1.20 | 1.40 | 0.047 | 0.055 | K | 0.01 | 0.10 | 0.0004 | 0.004 |
| C | - | 1.10 | - | 0.043 | L | 2.10 | 2.50 | 0.083 | 0.0985 |
| D | 0.37 | 0.53 | 0.015 | 0.021 | M | 0.45 | 0.64 | 0.018 | 0.025 |
| F | 0.085 | 0.15 | 0.0034 | 0.0059 | N | 0.95 NOM |  | 0.0375 NOM |  |
| G | 1.90 NOM |  | 0.075 NOM |  | - | - | - | - | - |

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

| Europe | Americas | Asia Pacific | Corporate Headquarters |
| :---: | :---: | :---: | :---: |
| Zetex GmbH | Zetex Inc | Zetex (Asia Ltd) | Zetex Semiconductors plc |
| Streitfeldstraße 19 | 700 Veterans Memorial Highway | 3701-04 Metroplaza Tower 1 | Zetex Technology Park, Chadderton |
| D-81673 München | Hauppauge, NY 11788 | Hing Fong Road, Kwai Fong | Oldham, OL9 9LL |
| Germany | USA | Hong Kong | United Kingdom |
| Telefon: (49) 894549490 | Telephone: (1) 6313602222 | Telephone: (852) 26100611 | Telephone: (44) 1616224444 |
| Fax: (49) 8945494949 europe.sales@zetex.com | Fax: (1) 6313608222 usa.sales@zetex.com | Fax: (852) 24250494 asia.sales@zetex.com | Fax: (44) 1616224446 hq@zetex.com |

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